TOSHIBA Photocoupler PHOTORELAY

## **TLP3250**

## Measurement Instruments Logic IC Testers / Memory Testers **Board Testers / Scanners**

The TOSHIBA TLP3250 is a super small-outline photorelay, suitable for surface-mount assembly. The TLP3250 consists of a GaAlAs infrared-emitting diode optically coupled to a photo-MOS FET and housed in a 4-pin package.

Its characteristics also include low OFF-state current and low output pin capacitance, enabling it to be used in high-frequency measuring instruments.

#### **Features**

4 pin SSOP (SSOP4) : 1.8 mm high, 1.27 mm pitch

1-Form-A

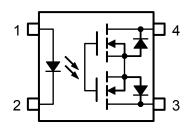
• Peak off-state voltage : 20 V (Min.) : 3 mA (Max.) • Trigger LED current : 200 mA (Max.) • On-state current :  $5\Omega$  (Max.),  $3\Omega$  (Typ.) On-state resistance Output capacitance : 1.1 pF (Max.), 0.8 pF (Typ.)

: 1500 Vrms (Min.) Isolation voltage

# Unit: mm Enlarged drawing is shown on page 4. JEDEC JEITA **TOSHIBA** 11-2B1

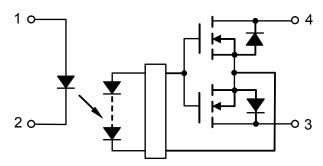
Weight: 0.03 g (Typ.)

### Pin configuration (top view)



- 1: Anode
- 2: Cathode
- 3 : Drain
- 4 : Drain

#### **Schematic**



#### Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current	ΙF	30	mA
	Forward current derating (Ta ≥ 25°C)	ΔI <sub>F</sub> /°C	-0.3	mA/°C
۳	Reverse voltage	V <sub>R</sub>	5	V
	Junction temperature	Tj	125	°C
	Off-State output terminal voltage	V <sub>OFF</sub>	20	V
Detector	On-State current	I <sub>ON</sub>	200	mA
Dete	On-State current derating (Ta ≧ 25°C)	Δl <sub>ON</sub> /°C	-2.0	mA/°C
	Junction temperature		125	°C
Stora	Storage temperature range		<b>−40~125</b>	°C
Oper	ating temperature range	T <sub>opr</sub>	-20~85	°C
Lead	soldering temperature (10 s)	T <sub>sol</sub>	260	°C
Isola	tion voltage (AC, 1 min., R.H. ≦ 60%) (Note 1)	BVS	1500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1): Device considered a two-terminal device: Pins 1 and 2 shorted together, and pins 3 and 4 shorted together.

#### Caution

This device is sensitive to electrostatic discharge. When using this device, please ensure that all tools and equipment are earthed.

#### **Recommended Operating Conditions**

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Forward current	l <sub>F</sub>	_	_	20	mA
Operating temperature	T <sub>opr</sub>	25	_	60	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

#### **Individual Electrical Characteristics (Ta = 25°C)**

	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
	Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 5 mA	1.15	1.30	1.45	V
LED	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 5 V	_	_	10	μА
	Capacitance	C <sub>T</sub>	V = 0, f = 1 MHz		30		pF
Detector	Off-state current	l <sub>OFF</sub>	V <sub>OFF</sub> = 20 V		10	200	рА
Dete	Capacitance	C <sub>OFF</sub>	V = 0, f = 100 MHz, t<1s	_	0.8	1.1	pF

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## **Coupled Electrical Characteristics (Ta = 25°C)**

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Trigger LED current	I <sub>FT</sub>	I <sub>ON</sub> = 100 mA	_	_	3	mA
Return LED current	I <sub>FC</sub>	I <sub>OFF</sub> = 1 μA	0.1	_	_	mA
On-state resistance	R <sub>ON</sub>	I <sub>ON</sub> = 200 mA, I <sub>F</sub> = 5 mA, t < 1 s	_	3	5	Ω

## Isolation Characteristics (Ta = 25°C)

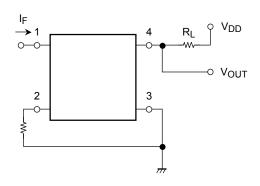
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance input to output	Cs	V <sub>S</sub> = 0 V, f = 1 MHz	_	0.6	_	pF
Isolation resistance	R <sub>S</sub>	V <sub>S</sub> = 500 V, R.H. ≤ 60%	5 × 10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
	BVS	AC, 1 minute	1500	_	_	Vrms
Isolation voltage		AC, 1 second (in oil)	_	3000	_	VIIIIS
		DC, 1 minute (in oil)	_	3000	_	Vdc

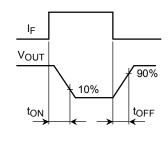
## **Switching Characteristics (Ta = 25°C)**

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Turn-on time	t <sub>ON</sub>	$R_L = 200 \Omega$ (Note 2)	_	26	200	6
Turn-off time	t <sub>OFF</sub>	$V_{DD} = 10 \text{ V}, I_F = 5 \text{ mA}$	_	45	200	μS

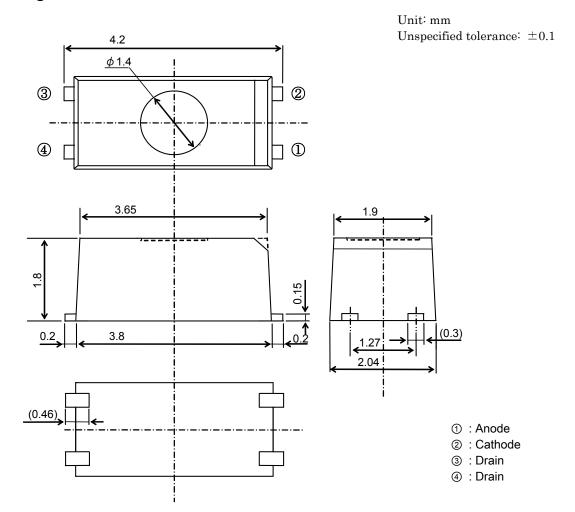
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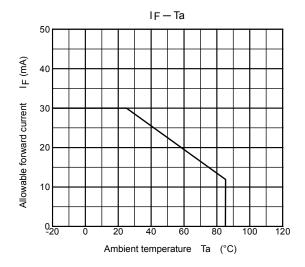
(Note 2): switching time test circuit

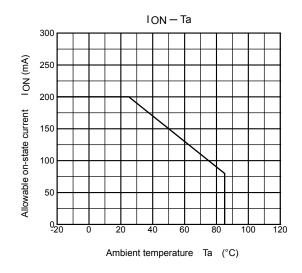


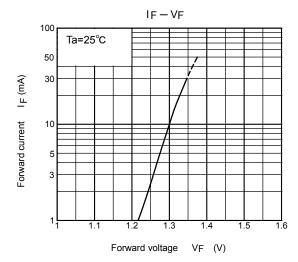


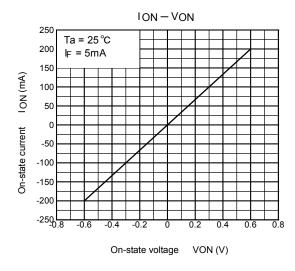
## **Outline Drawing**

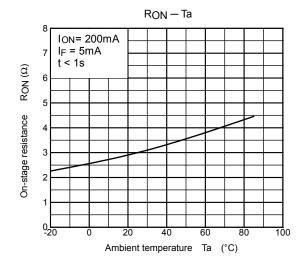


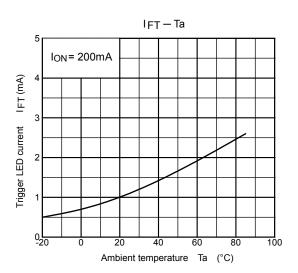


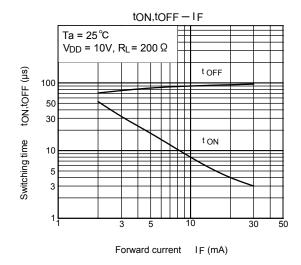


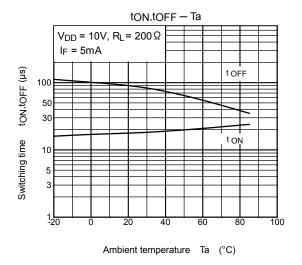


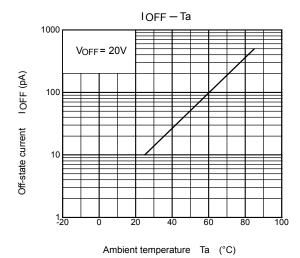












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